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CBT3253

Dual 1-of-4 FET multiplexer/demultiplexer Rev. 2 — 3 December 2014

Product data sheet

1. **General description**

The CBT3253 is a dual 1-of-4 high-speed TTL-compatible FET multiplexer/demultiplexer. The low ON-resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

The select control inputs (S0, S1) can select the data path, when both output enable inputs (1OE, 2OE) are LOW. When nOE is HIGH, the switch terminals are in the high impedance OFF-state, independent of S0 and S1.

The CBT3253 is characterized for operation from -40 °C to +85 °C.

2. Features and benefits

- \blacksquare 5 Ω switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- Latch-up protection exceeds 100 mA per JEDEC standard JESD78 class II level A
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C

3. Ordering information

Table 1. **Ordering information**

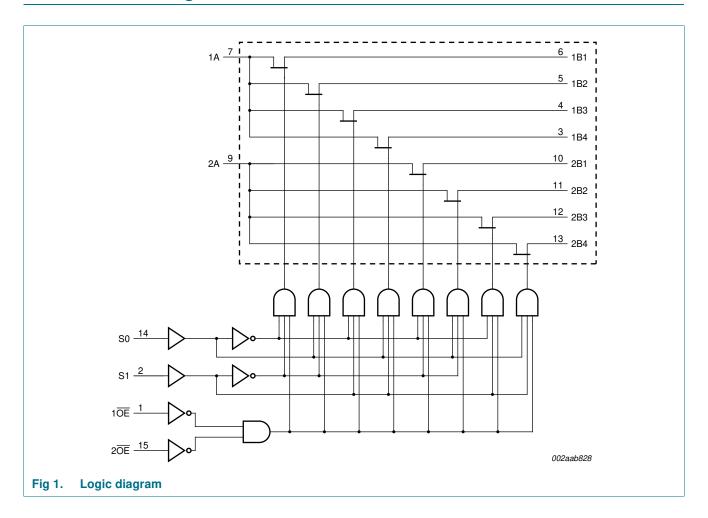
Type number	Temperature range	Package	Package						
		Name	Description	Version					
CBT3253D	–40 °C to +85 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
CBT3253DB	–40 °C to +85 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
CBT3253DS	–40 °C to +85 °C	SSOP16[1]	plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm	SOT519-1					
CBT3253PW	–40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					

[1] Also known as QSOP16.



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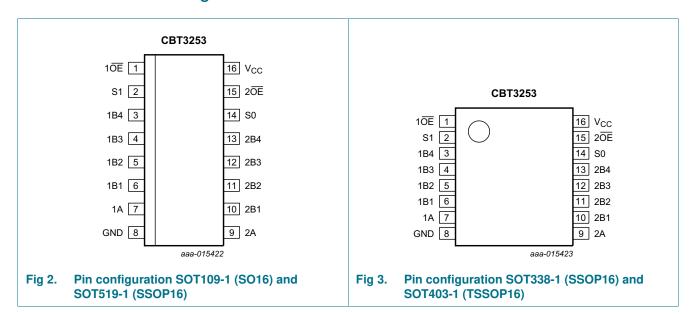
4. Functional diagram



Dual 1-of-4 FET multiplexer/demultiplexer

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
10E, 20E	1, 15	output enable (active LOW)
S1, S0	2, 14	select control input
1B4, 1B3, 1B2, 1B1	3, 4, 5, 6	1B outputs/inputs
1A	7	1A input/output
GND	8	ground (0 V)
2A	9	2A input/output
2B1, 2B2, 2B3, 2B4	10, 11, 12, 13	2B outputs/inputs
V _{CC}	16	positive supply voltage

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6. Functional description

Table 3. Function selection

H = HIGH voltage level; L = LOW voltage level; X = Don't care.

Inputs	•			Switch
10E	2OE	S1	S0	
Χ	Н	Х	Х	disconnect 1A to 1Bn and 2A to 2Bn
Н	Х	Х	Х	disconnect 1A to 1Bn and 2A to 2Bn
L	L	L	L	1A to 1B1 and 2A to 2B1
L	L	L	Н	1A to 1B2 and 2A to 2B2
L	L	Н	L	1A to 1B3 and 2A to 2B3
L	L	Н	Н	1A to 1B4 and 2A to 2B4

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
V _I	input voltage	[1]	-0.5	+7.0	V
I _{SW}	switch current	continuous current through each switch	-	128	mA
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$			
		SO16 package	-	500	mW
		SSOP16 package [3]	-	500	mW
		TSSOP16 package	-	500	mW

^[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

8. Recommended operating conditions

Table 5. Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		4.5	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	V
V_{IL}	LOW-level input voltage		-	0.8	V
T _{amb}	ambient temperature	operating in free-air	-40	+85	°C

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

^[3] For SSOP16 and TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 70 °C.

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9. Static characteristics

Table 6. Static characteristics

 $T_{amb} = -40$ °C to +85 °C.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V _{IK}	input clamping voltage	$V_{CC} = 4.5 \text{ V}; I_I = -18 \text{ mA}$	-	-	-1.2	V
V _{pass}	pass voltage	$V_I = V_{CC} = 5.0 \text{ V}; I_O = -100 \mu\text{A}$	3.6	3.9	4.2	V
l _l	input leakage current	V _{CC} = 5.5 V; V _I = GND or 5.5 V	-	-	±1	μΑ
I _{CC}	supply current	V_{CC} = 5.5 V; I_O = 0 mA; V_I = V_{CC} or GND	-	-	3	μА
ΔI_{CC}	additional supply current	per input; $V_{CC} = 5.5 \text{ V}$; one input at 3.4 V, other inputs at V_{CC} or GND	1 -	-	2.5	mA
Cı	input capacitance	control pins; V _I = 3 V or 0 V	-	4.5	-	рF
C _{io(off)}	off-state input/output capacitance	A port; $V_O = 3 \text{ V or } 0 \text{ V}$; $n\overline{OE} = V_{CC}$	-	11.4	-	рF
		B port; $V_O = 3 \text{ V or } 0 \text{ V; } n\overline{OE} = V_{CC}$	-	3.8	-	pF
C _{io(on)}	on-state input/output capacitance	A port and B port	-	18.6	-	рF
R _{ON}	ON resistance	V _{CC} = 4.5 V]	'	1	
		V _I = 0 V; I _I = 64 mA	-	5	7	Ω
		V _I = 0 V; I _I = 30 mA	-	5	7	Ω
		V _I = 2.4 V; I _I = -15 mA	-	10	15	Ω

^[1] All typical values are measured at V_{CC} = 5 V; T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_{amb} = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$; $V_{CC} = 4.5 \, \text{V}$ to 5.5 V; for test circuit, see <u>Figure 6</u>.

Symbol	Parameter	Conditions		Min	Max	Unit
t _{pd}	propagation delay	nA to nBn or nBn to nA; see Figure 4	[1][2]	-	0.25	ns
		Sn to nA; see Figure 4	[1][2]	1.2	6.2	ns
t _{en}	enable time	Sn to nBn; see Figure 5	[2]	1.3	6.3	ns
		nOE to nA or nBn; see Figure 5	[2]	1.4	6.4	ns
t _{dis}	disable time	Sn to nBn; see Figure 5	[2]	1.1	7.2	ns
		nOE to nA or nBn; see Figure 5	[2]	1.0	7	ns

^[1] This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON resistance of the switch and a load capacitance, when driven by an ideal voltage source (zero output impedance).

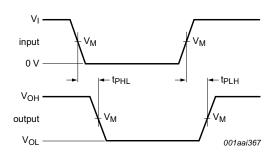
[2] t_{PLH} and t_{PHL} are the same as t_{pd} . t_{PZL} and t_{PZH} are the same as t_{en} . t_{PLZ} and t_{PHZ} are the same as t_{dis} .

^[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

^[3] Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. The lowest voltage of the two (A or B) terminals determines the ON resistance.

Dual 1-of-4 FET multiplexer/demultiplexer

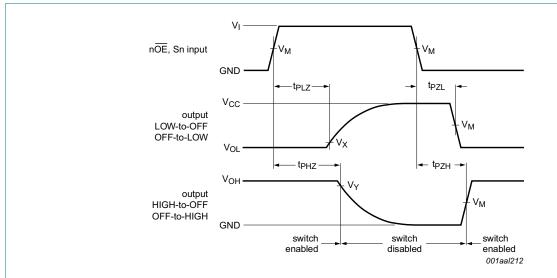
11. AC waveforms



Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 4. The input (nA, nBn) to output (nBn, nA) or input (Sn) to output (nA) propagation delay times



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

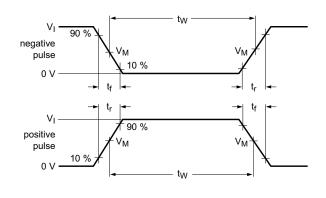
Fig 5. Enable and disable times

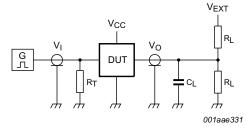
Table 8. Measurement points

Supply voltage	Input		Output				
V _{CC}	cc V _I V _M		V _M	V _X	V _Y		
4.5 V to 5.5 V	GND to 3.0 V	1.5 V	1.5 V	V _{OL} + 0.3 V	$V_{OH} - 0.3 V$		

Dual 1-of-4 FET multiplexer/demultiplexer

12. Test information





Test data is given in Table 9.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 6. Test circuit for measuring switching times

Table 9. Test data

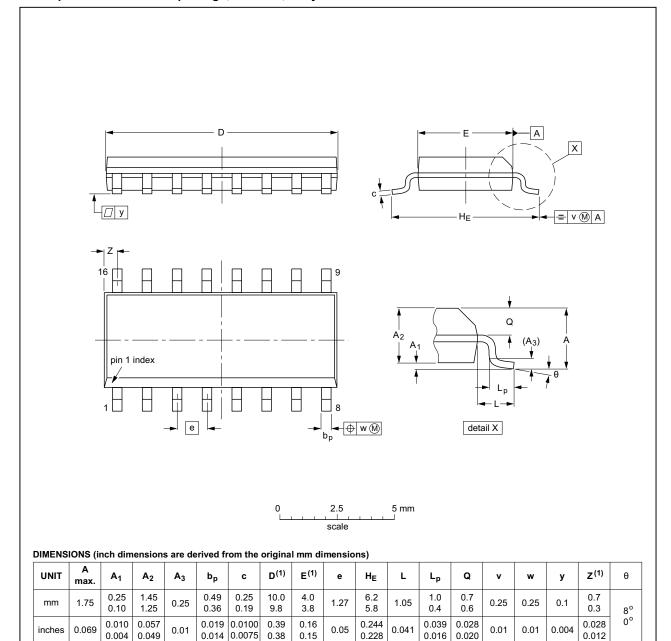
Supply voltage	oltage Input				V _{EXT}			
V _{CC}	V _I t _r , t _f		C _L R _L t		t _{PLH} , t _{PHL} t _{PLZ} , t _{PZL}		t _{PHZ} , t _{PZH}	
4.5 V to 5.5 V	GND to 3.0 V	≤ 2.5 ns	50 pF	500 Ω	open	7.0 V	open	

Dual 1-of-4 FET multiplexer/demultiplexer

13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 7. Package outline SOT109-1 (SO16)

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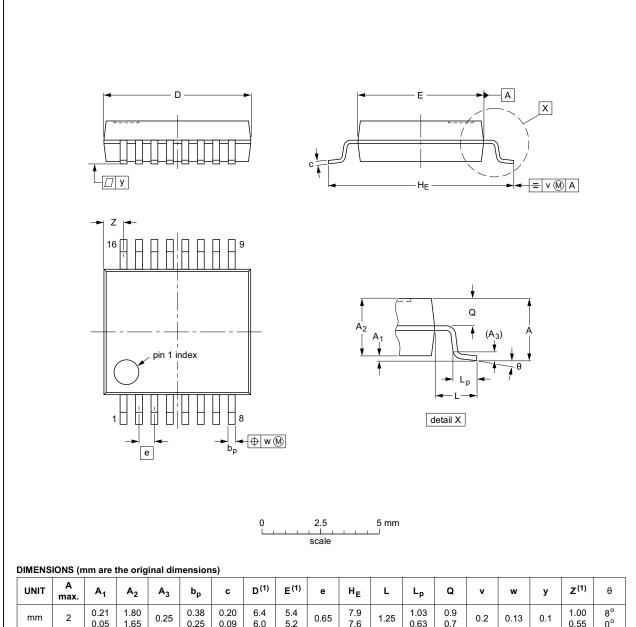
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Dual 1-of-4 FET multiplexer/demultiplexer

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION		REFER	ENCES	EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT338-1		MO-150			99-12-27 03-02-19

Package outline SOT338-1 (SSOP16) Fig 8.

CBT3253

Product data sheet

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SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

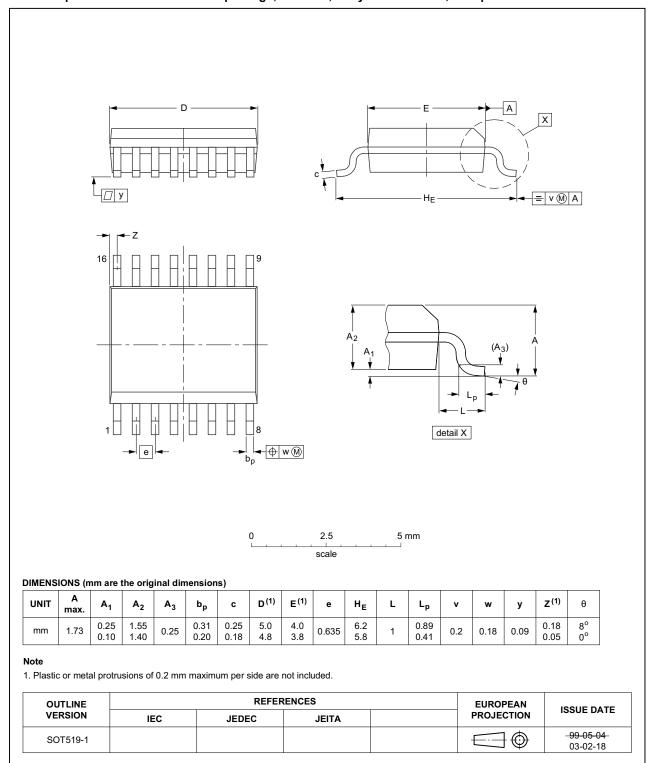


Fig 9. Package outline SOT519-1 (SSOP16)

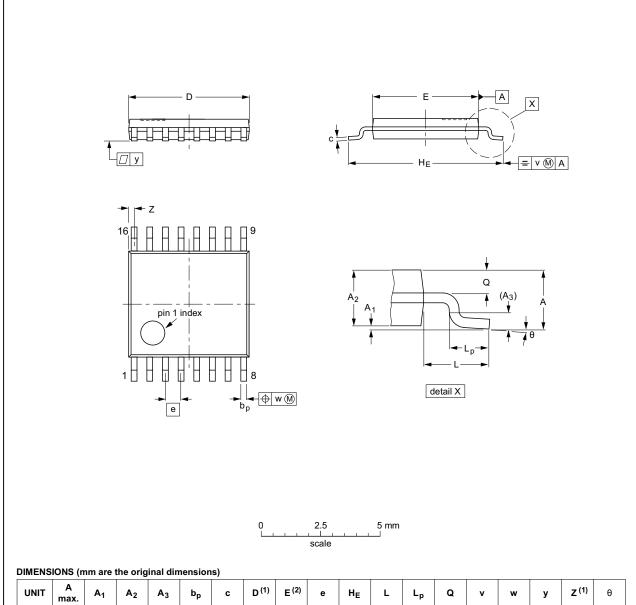
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Dual 1-of-4 FET multiplexer/demultiplexer

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

		ISSUE DATE	
JEDEC JEITA	PROJECTION		
MO-153		99-12-27 03-02-18	
		JEDEC JEHA	

Fig 10. Package outline SOT403-1 (TSSOP16)

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Dual 1-of-4 FET multiplexer/demultiplexer

14. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
CBT3253 v.2	20141203	Product data sheet	-	CBT3253 v.1				
Modifications:	The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.							
	 Legal texts have been adapted to the new company name where appropriate. <u>Section 1 "General description"</u>: text changed to align with the function of the device. 							
Figure 1 "Logic diagram": schematic changed.								
	• Table 3 "Function selection": switch description changed to align with the function of the							
<u>Table 6 "Static characteristics":</u>								
	- C _{io(off)} , B pc	6.5 pF to 3.8 pF						
	 added C_{io(on)} specification 							
<u>Table 6 "Static characteristics"</u> : values for pass voltage modified.								
CBT3253 v.1	20021104	Product data sheet	-	-				

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Dual 1-of-4 FET multiplexer/demultiplexer

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